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Semiconductor Optical Amplifier Device (Switch-type)

IPSAD1302/ IPSAD1502 (1310nm/1550nm)

Features

- Wide Optical Bandwidth
- Fast Switching Speed
- High Extinction Ratio
- Low Polarization Sensitivity
- MQW or Bulk Structure



Applications

- Optical Gate Switching with Loss Compensation
- Wavelength Routing
- Matrix Switch

IPSAD1302 Switch-type SOA Device Specifications

Parameter		Symbol	Specifications			Unit
			Min.	Тур.	Max.	Unit
Drive Current		I_F		100	150	mA
Operating Peak Wavelength		λ_{p}	1280		1340	nm
3 dB Optical Bandwidth		$\Delta \lambda_{3 ext{dB}}$	50			nm
Small Signal Gain at λ _p @ -25 dBm		G_{max}		10		dB
Signal						
Gain Ripple with Respect to λ		ΔG		0.2	0.5	dB
Saturation Output Power		P_{sat}	4			dBm
Noise Figure		NF		8		dB
Polarization Dependent Gain		PDG		0.2	0.5	dB
Extinction Ratio		ER	40			dB
Switching Properties	Rise Time	τ_{r}		500		ps
	Fall Time	$ au_{\mathrm{f}}$		500		ps

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IPSAD1502 Switch-type SOA Device Specifications

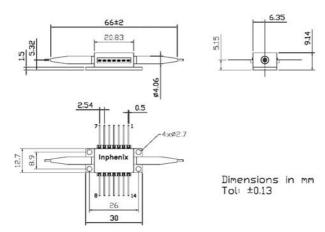
Parameter		Symbol	Specifications			Unit
			Min.	Typ.	Max.	Unit
Drive Current		I_{F}		120	180	mA
Operating Peak Wavelength		λ_{p}	1510		1570	nm
3 dB Optical Bandwidth		$\Delta \lambda_{3 ext{dB}}$	50			nm
Small Signal Gain at λ _p @ -25 dBm		G_{max}		10		dB
Signal						
Gain Ripple with Respect to λ		ΔG		0.2	0.5	dB
Saturation Output Power		P_{sat}	3			dBm
Noise Figure		NF		10		dB
Polarization Dependent Gain		PDG		0.2	0.5	dB
Extinction Ratio		ER	40			dB
Switching Properties	Rise Time	τ_{r}		500		ps
	Fall Time	$ au_{ m f}$		500		ps

Absolute Maximum Ratings

Parameter	Min.	Max.	Unit	
Operating Temperature	-20	70	°C	
Storage Temperature	- 40	85	°C	
SOA Forward Current		300	mA	
SOA Reverse Voltage		2.5	V	
TEC Drive Current		1.5	A	
TEC Drive Voltage		3.6	V	
Thermistor Resistance	10 kΩ @ 25 °C			
SOA Chip Temperature Setting	25 °C			
Fiber Type	SMF			
Fiber Jacket	900 μm or 250 μm tight buffer			
Package	14-pin Butterfly			

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Package Dimensions



Pin Definition

Pin	14-pin Butterfly		
1	TEC(+)		
2	NC		
3	Thermistor		
4	Thermistor		
5	NC		
6	NC		
7	NC		
8	NC		
9	NC		
10	SOA(+)		
11	SOA(-)		
12	NC		
13	Case		
14	TEC(-)		

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Part Numbering Structure

	IPSAD1302	
	a Switch-type SOA Device a Switch-type SOA Device	
Package- 1: Deleted 2: 14-pin Butterfly		
Fiber Type: 1- 900 μm SM Fiber 2- 250 μm SM Fiber		
Connector Type:		
0=No Connectors 1=Deleted 2= Deleted 3=FC/APC 4=FC/UPC	5= Deleted 6= Deleted 7=SC/APC 8=SC/UPC	

Example: IPSAD1302-110: 1310 nm Switch-type SOA in 14-pin Butterfly Package with 900 μ m SM Fiber with no Connectors.

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